Midium Power Transistors (30V / 3A)

QS5W1

● Structure

NPN Silicon epitaxial planar transistor

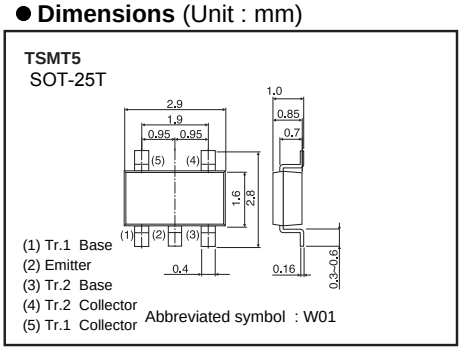
● Features

1) Low saturation voltage
   $V_{CE\ (sat)}$ = 0.4V (Max.) (I_C / I_B= 1A / 50mA)
2) High speed switching

● Applications

Low Frequency Amplifier
Driver

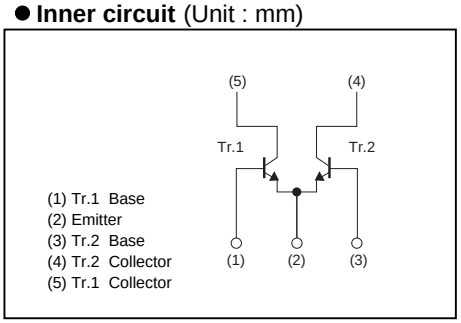
● Dimensions (Unit : mm)



● Packaging specifications

Type	Package	TSMT5
	Code	TR
	Basic ordering unit (pieces)	3000

● Inner circuit (Unit : mm)



● Absolute maximum ratings (Ta = 25°C)

<It is the same ratings for the Tr.1 and Tr.2>

Parameter		Symbol	Limits	Unit
Collector-base voltage		V_{CBO}	30	V
Collector-emitter voltage		V_{CEO}	30	V
Emitter-base voltage		V_{EBO}	6	V
Collector current	DC	I_C	3	A
	Pulsed	I_{CP} *1	6	A
Power dissipation		P_D *2	0.5	W/Total
		P_D *3	1.25	W/Total
		P_D *3	0.9	W/Element
Junction temperature		T_j	150	°C
Range of storage temperature		T_{stg}	-55 to 150	°C

*1 Pw=10ms, Single Pulse

*2 Mounted on a recommended land.

*3 Mounted on a 25 x 25 x 0.8[mm] ceramic board.

●**Electrical characteristics** (Ta=25°C)

<It is the same ratings for the Tr.1 and Tr.2>

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-emitter breakdown voltage	BV_{CEO}	30	-	-	V	I_C= 1mA
Collector-base breakdown voltage	BV_{CBO}	30	-	-	V	I_C= 100μA
Emitter-base breakdown voltage	BV_{EBO}	6	-	-	V	I_E= 100μA
Collector cut-off current	I_{CBO}	-	-	1	μA	V_{CB}= 30V
Emitter cut-off current	I_{EBO}	-	-	1	μA	V_{EB}= 4V
Collector-emitter staturation voltage	$V_{CE(sat)}$ *1	-	200	400	mV	I_C= 1A, I_B= 50mA
DC current gain	h_{FE}	200	-	500	-	V_{CE}= 2V, I_C= 500mA
Transition frequency	f_T *1	-	270	-	MHz	V_{CE}= 10V I_E=-100mA, f=100MHz
Collector output capacitance	C_{ob}	-	16	-	pF	V_{CB}= 10V, I_E=0A f=1MHz
Turn-on time	t_{on} *2	-	25	-	ns	I_C= 1.5A, I_{B1}= 150mA, I_{B2}=-150mA, V_{CC}≒12V
Storage time	t_{stg} *2	-	300	-	ns	
Fall time	t_f *2	-	20	-	ns	

*1 Pulsed

*2 See switching time test circuit

●Electrical characteristic curves (Ta=25°C)

Fig.1 Typical Output Characteristics

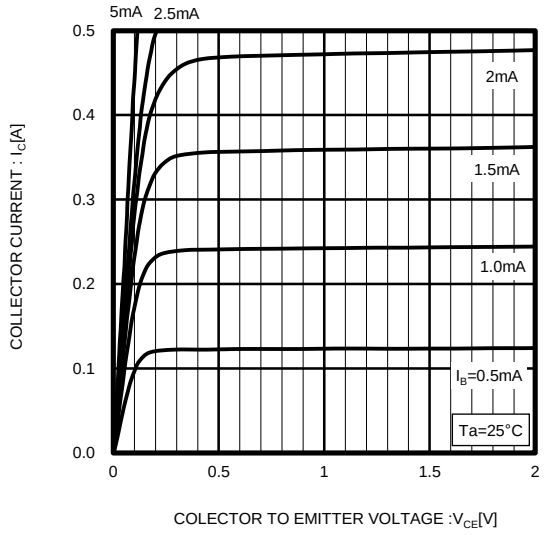


Fig.2 DC Current Gain vs. Collector Current (I)

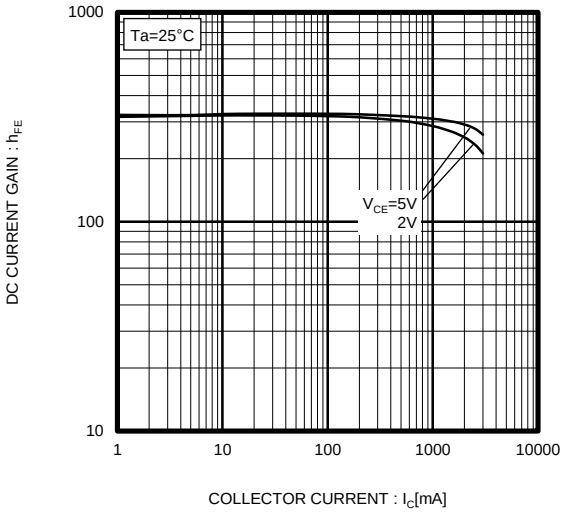


Fig3. DC Current Gain vs. Collector Current (II)

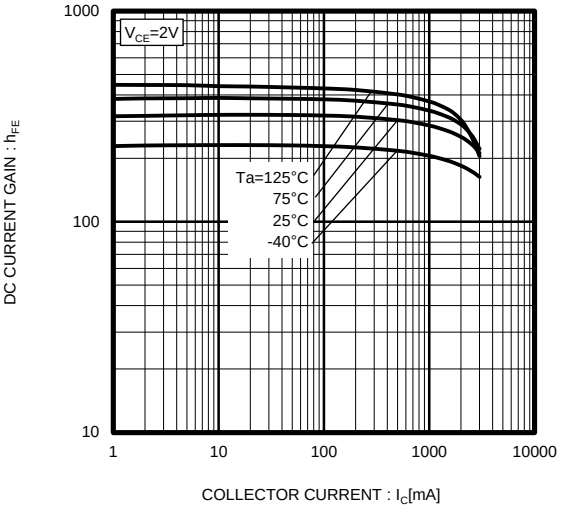


Fig.4 Collector-Emitter Saturation Voltage vs. Collector Current (I)

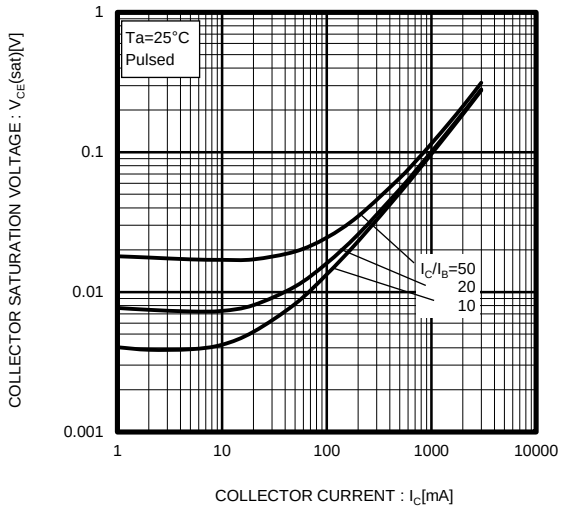


Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current (II)

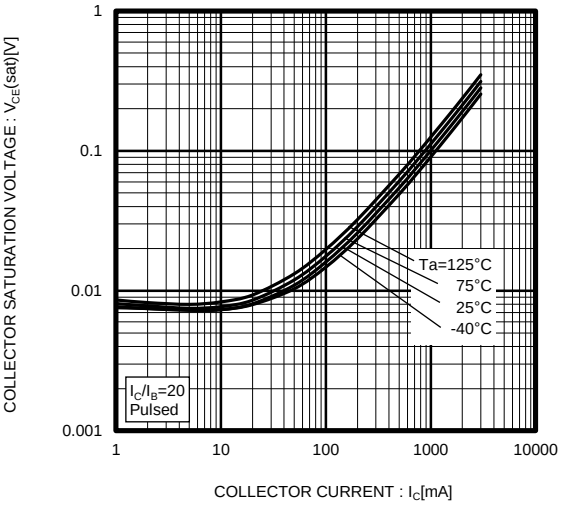


Fig.6 Ground Emitter Propagation Characteristics

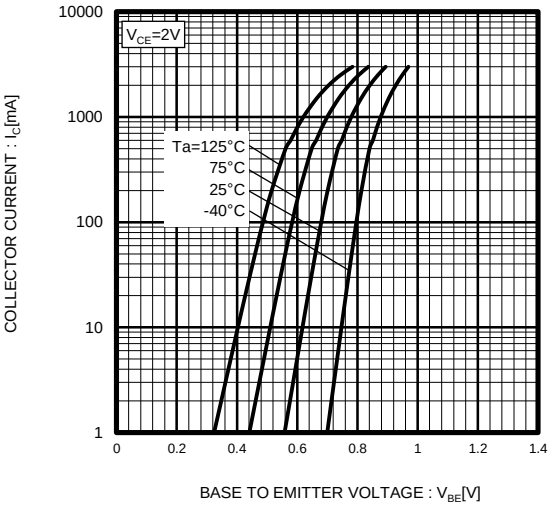


Fig.7 Emitter Input Capacitance vs. Emitter-Base Voltage
Collector Output Capacitance vs. Collector-Base Voltage

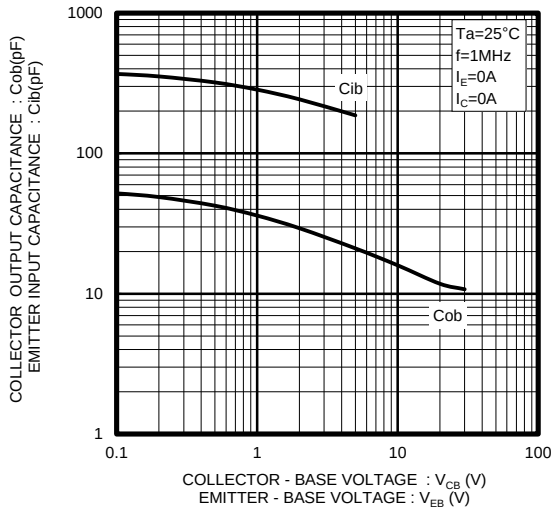


Fig.8 Gain Bandwidth Product vs. Emitter Current

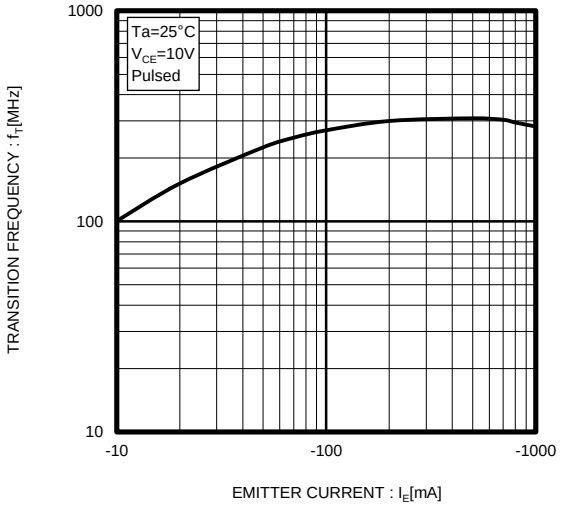
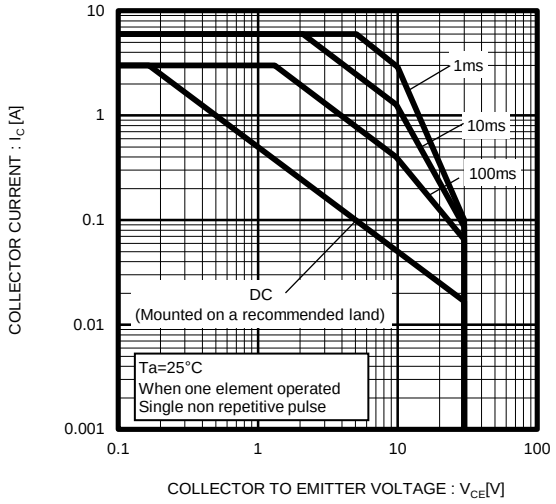
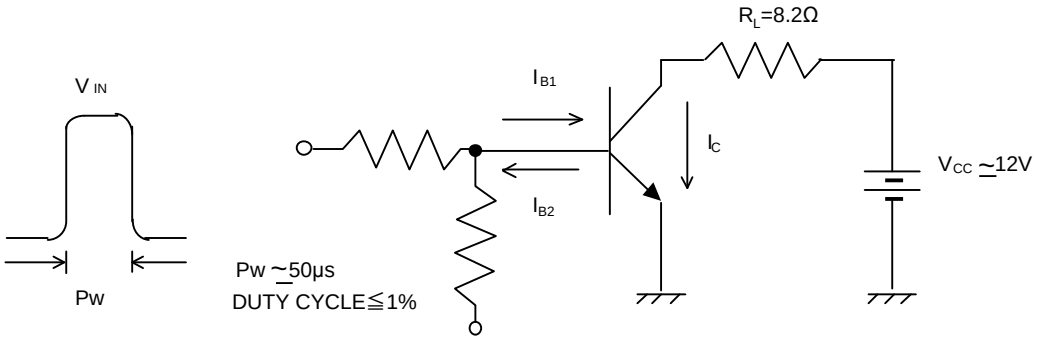


Fig.9 Safe Operating Area

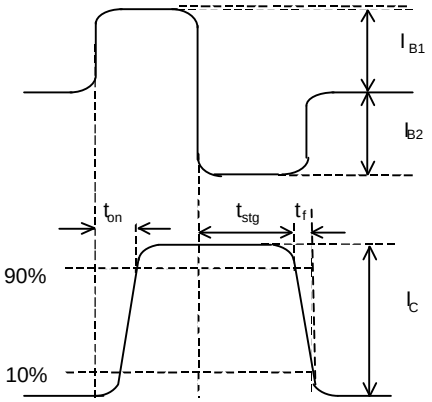


● **Switching time test circuit**



BASE CURENT WAVEFORM

COLLECTOR CURRENT WAVEFORM



Notes

No copying or reproduction of this document, in part or in whole, is permitted without the consent of ROHM Co.,Ltd.

The content specified herein is subject to change for improvement without notice.

The content specified herein is for the purpose of introducing ROHM's products (hereinafter "Products"). If you wish to use any such Product, please be sure to refer to the specifications, which can be obtained from ROHM upon request.

Examples of application circuits, circuit constants and any other information contained herein illustrate the standard usage and operations of the Products. The peripheral conditions must be taken into account when designing circuits for mass production.

Great care was taken in ensuring the accuracy of the information specified in this document. However, should you incur any damage arising from any inaccuracy or misprint of such information, ROHM shall bear no responsibility for such damage.

The technical information specified herein is intended only to show the typical functions of and examples of application circuits for the Products. ROHM does not grant you, explicitly or implicitly, any license to use or exercise intellectual property or other rights held by ROHM and other parties. ROHM shall bear no responsibility whatsoever for any dispute arising from the use of such technical information.

The Products specified in this document are intended to be used with general-use electronic equipment or devices (such as audio visual equipment, office-automation equipment, communication devices, electronic appliances and amusement devices).

The Products specified in this document are not designed to be radiation tolerant.

While ROHM always makes efforts to enhance the quality and reliability of its Products, a Product may fail or malfunction for a variety of reasons.

Please be sure to implement in your equipment using the Products safety measures to guard against the possibility of physical injury, fire or any other damage caused in the event of the failure of any Product, such as derating, redundancy, fire control and fail-safe designs. ROHM shall bear no responsibility whatsoever for your use of any Product outside of the prescribed scope or not in accordance with the instruction manual.

The Products are not designed or manufactured to be used with any equipment, device or system which requires an extremely high level of reliability the failure or malfunction of which may result in a direct threat to human life or create a risk of human injury (such as a medical instrument, transportation equipment, aerospace machinery, nuclear-reactor controller, fuel-controller or other safety device). ROHM shall bear no responsibility in any way for use of any of the Products for the above special purposes. If a Product is intended to be used for any such special purpose, please contact a ROHM sales representative before purchasing.

If you intend to export or ship overseas any Product or technology specified herein that may be controlled under the Foreign Exchange and the Foreign Trade Law, you will be required to obtain a license or permit under the Law.

ROHM SEMICONDUCTOR

Thank you for your accessing to ROHM product informations.
More detail product informations and catalogs are available, please contact us.

ROHM Customer Support System

http://www.rohm.com/contact/

LifeElectronics
Живое партнерство

ООО «ЛайфЭлектроникс» **“LifeElectronics” LLC**

ИНН 7805602321 КПП 780501001 Р/С 40702810122510004610 ФАКБ "АБСОЛЮТ БАНК" (ЗАО) в г.Санкт-Петербурге К/С 30101810900000000703 БИК 044030703

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- *Конкурентоспособные цены и скидки постоянным клиентам.*
- *Специальные условия для постоянных клиентов.*
- *Подбор аналогов.*
- *Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.*

- *Приемлемые сроки поставки, возможна ускоренная поставка.*
- *Доставку товара в любую точку России и стран СНГ.*
- *Комплексную поставку.*
- *Работу по проектам и поставку образцов.*
- *Формирование склада под заказчика.*

- *Сертификаты соответствия на поставляемую продукцию (по желанию клиента).*
- *Тестирование поставляемой продукции.*
- *Поставку компонентов, требующих военную и космическую приемку.*
- *Входной контроль качества.*
- *Наличие сертификата ISO.*

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- *Регистрацию проекта у производителя компонентов.*
- *Техническую поддержку проекта.*
- *Защиту от снятия компонента с производства.*
- *Оценку стоимости проекта по компонентам.*
- *Изготовление тестовой платы монтаж и пусконаладочные работы.*

Тел: +7 (812) 336 43 04 (многоканальный)
Email: org@lifeelectronics.ru

www.lifeelectronics.ru